INTEGRATED CIRCUITS

DATA SHEET

74LVT162244B

3.3V 16-bit buffer/driver with 30Ω termination resistors

Product specification Supersedes data of 1998 Feb 19 IC23 Data Handbook





3.3V 16-bit buffer/driver with 30 Ω termination resistors (3-State)

74LVT162244B

FEATURES

- 16-bit bus interface
- 3-State buffers
- Output capability: +12mA/-12mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- ullet Outputs include series resistance of 30Ω making external terminating resistors unnecessary
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model
- Same part as 74LVT16244B-1

DESCRIPTION

The 74LVT162244B is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

The 74LVT162244B is designed with 30Ω series resistance in both the High and Low states of the output. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus receivers/transmitters.

This device is a 16-bit buffer and line driver featuring non-inverting 3-State bus outputs. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer.

The 74LVT162244B is the same as the 74LVT16244B-1. The part number has been changed to reflect industry standards.

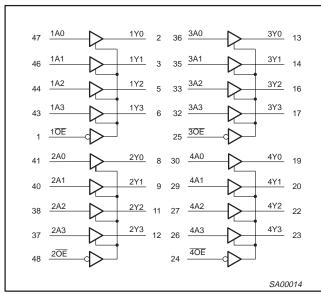
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C	TYPICAL	UNIT	
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	$C_L = 50pF;$ $V_{CC} = 3.3V$	2.8	ns	
C _{IN}	Input capacitance nOE	V _I = 0V or 3.0V	3	pF	
C _{OUT}	Output capacitance	Outputs disabled; $V_O = 0V$ or 3.0V	9	pF	
I _{CCZ}	Total supply current	Outputs disabled; V _{CC} = 3.6V	70	μΑ	

ORDERING INFORMATION

OTTO LITTLE OTTO				
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to +85°C	74LVT162244B DL	VT162244B DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74LVT162244B DGG	VT162244B DGG	SOT362-1

LOGIC SYMBOL



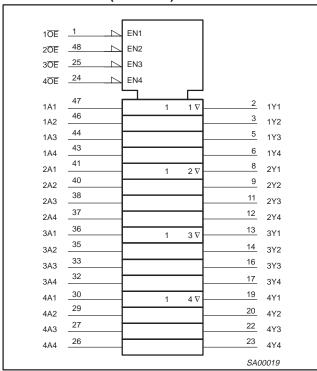
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
47, 46, 44, 43 41, 40, 38, 37 36, 35, 33, 32 30, 29, 27, 26	1A0 - 1A3, 2A0 - 2A3, 3A0 - 3A3, 4A0 - 4A3	Data inputs
2, 3, 5, 6 8, 9, 11, 12 13, 14, 16, 17 19, 20, 22, 23	1Y0 - 1Y3, 2Y0 - 2Y3, 3Y0 - 3Y3, 4Y0 - 4Y3	Data outputs
1, 48 25, 24	1 0E , 2 0E , 3 0E , 4 0E	Output enables
4, 10, 15, 21 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{CC}	Positive supply voltage

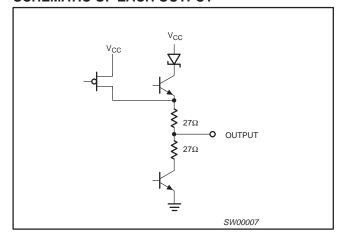
3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

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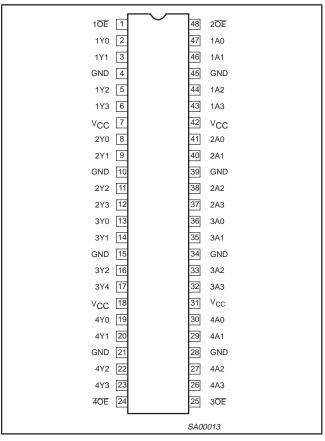
LOGIC SYMBOL (IEEE/IEC)



SCHEMATIC OF EACH OUTPUT



PIN CONFIGURATION



FUNCTION TABLE

	<u> </u>								
INP	OUTPUTS								
nOE	nAx	nYx							
L	L	L							
L	Н	Н							
Н	Х	z							

H = High voltage level

L = Low voltage level

X = Don't care

Z = High Impedance "off" state

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ABSOLUTE MAXIMUM RATINGS1, 2

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
lok	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
	DC output ourrent	Output in Low state	128	A
Гоит	DC output current	Output in High state	-64	mA
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT		
STWIBUL	PARAMETER	MIN	MAX	UNII	
V _{CC}	DC supply voltage	2.7	3.6	V	
V_{I}	Input voltage	0	5.5	V	
V_{IH}	High-level input voltage	2.0		V	
V_{IL}	Input voltage		0.8	V	
I _{OH}	High-level output current		-12	mA	
I _{OL}	Low-level output current		12	mA	
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10	ns/V	
T _{amb}	Operating free-air temperature range	-40	+85	°C	

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

^{3.} The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

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DC ELECTRICAL CHARACTERISTICS

					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	Temp =	-40°C to	0°C to +85°C		
			MIN	TYP ¹	MAX	1	
V _{IK}	Input clamp voltage	V _{CC} = 2.7V; I _{IK} = -18mA				-1.2	
V _{OH}	High-level output voltage	V _{CC} = 3.0V; I _{OH} = -12mA		2.0			V
V _{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 12mA				0.8	1
		$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND	Control pins		0.1	±1.0	
	land balance and	V _{CC} = 0 or 3.6V; V _I = 5.5V			0.4	10	1 ,
tı	Input leakage current	V _{CC} = 3.6V; V _I = V _{CC}	5 4		0.1	1	μΑ
		V _{CC} = 3.6V; V _I = 0	Data pins ⁴		-0.4	-5	
I _{OFF}	Output off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$	$V_{CC} = 0V$; V_I or $V_O = 0$ to 4.5V			±100	μА
		$V_{CC} = 3V; V_I = 0.8V$		75	135		
I_{HOLD}	Bus Hold current A inputs ⁶	$V_{CC} = 3V; V_{I} = 2.0V$		-75	-135		μΑ
		$V_{CC} = 0V \text{ to } 3.6V; V_{CC} = 3.6V$		±500			
I _{EX}	Current into an output in the High state when V _O > V _{CC}	V _O = 5.5V; V _{CC} = 3.0V			50	125	μА
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = GND$ OE/ $\overline{OE} = Don't$ care	or V _{CC} ;		1	±100	μΑ
I _{OZH}	3-State output High current	$V_{CC} = 3.6V$; $V_{O} = 3.0V$; $V_{I} = V_{IL}$ or V_{IH}			0.5	5	μΑ
I _{OZL}	3-State output Low current	$V_{CC} = 3.6V$; $V_{O} = 0.5V$; $V_{I} = V_{IL}$ or V_{IH}			0.5	-5	μΑ
I _{CCH}		$V_{CC} = 3.6V$; Outputs High, $V_I = GND$ or V_{CC} , $I_{O} = 0$			0.07	0.12	
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_I = GND$ or V_{CC} , $I_{O} = 0$			4.0	6.0	mA
I _{CCZ}	1	$V_{CC} = 3.6V$; Outputs Disabled; $V_I = GND$		0.07	0.12]	
Δl _{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V_{CC} -0.6\ Other inputs at V_{CC} or GND	/,		0.1	0.2	mA

- All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
 This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
 This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V and 1.2V with a transition time of up to 10msec. transition time of 100 μ sec is permitted. This parameter is valid for $T_{amb} = 25^{\circ}C$ only. 4. Unused pins at V_{CC} or GND.

- 5. I_{CCZ} is measured with outputs pulled to V_{CC} or GND.
 6. This is the bus hold overdrive current required to force the input to the opposite logic state.

AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5 \text{ns}$; $C_L = 50 \text{pF}$; $R_L = 500 \Omega$; $T_{amb} = -40 ^{\circ} \text{C}$ to $+85 ^{\circ} \text{C}$.

				LI	MITS		
SYMBOL	PARAMETER WAVEFORM		V _C	c = 3.3V ±0.	.3V	V _{CC} = 2.7V	UNIT
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	0.5 0.5	2.8 2.5	4.2 4.2	5.0 5.0	ns
^t PZH ^t PZL	Output enable time to High and Low level	2	1.0 1.0	3.5 3.1	5.5 5.5	7.0 6.5	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	2	1.0 1.0	3.6 3.1	5.5 5.5	6.0 6.0	ns

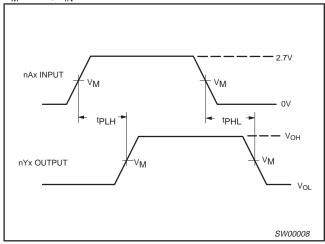
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

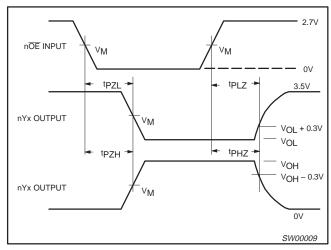
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AC WAVEFORMS

 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 3.0V$

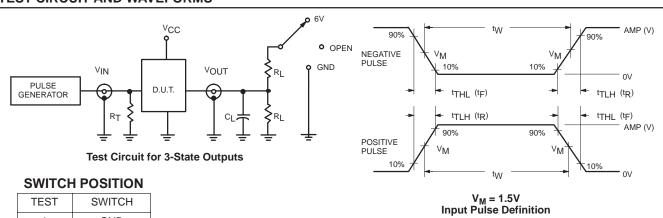


Waveform 1. Input (nAx) to Output (nYx) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

TEST CIRCUIT AND WAVEFORMS



TEST	SWITCH
t _{PHZ} /t _{PZH}	GND
t _{PLZ} /t _{PZL}	6V
t _{PLH} /t _{PHL}	open

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$ capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 $R_T = Termination resistance should be equal to <math>Z_{OUT}$ of pulse generators.

FAMILY	INPUT PULSE REQUIREMENTS									
FAMILI	Amplitude	Rep. Rate	t _W t _R		t _F					
74LVT16	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns					

SW00003

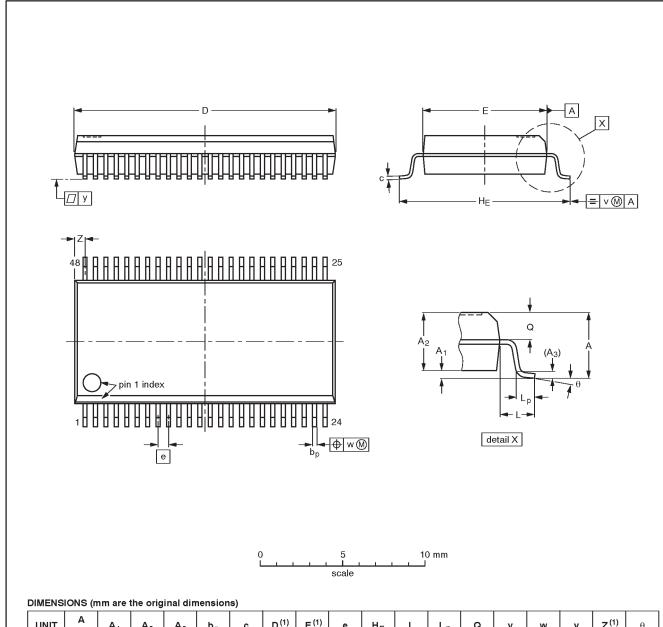
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3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

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SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



UNIT	A max.	Α1	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

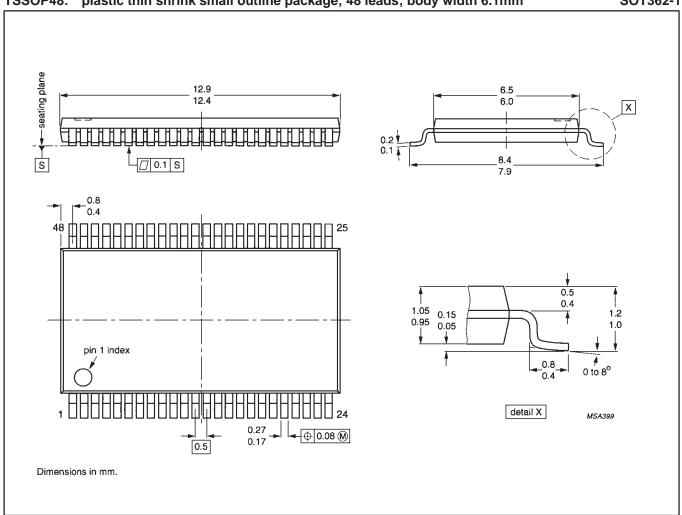
OUTLINE		REFER	RENCES		EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION		ISSUE DATE	
SOT370-1		MO-118AA				93-11-02 95-02-04	

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3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

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TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm SOT362-1



3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

74LVT162244B

NOTES

3.3V LVT 16-bit buffer/driver with 30Ω termination resistors (3-State)

74LVT162244B

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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